TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR ILICON PLANAR TYPE

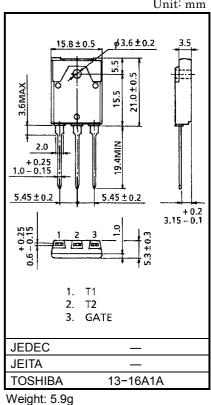
SM25GZ51,SM25JZ51

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V_{DRM} = 400, 600V
- R.M.S On-State Current
- : IT (RMS) = 25A
- High Commutating (dv / dt)
- $(dv / dt) c = 10V / \mu s$ $: V_{Isol} = 1500 V AC$
- **Isolation Voltage**

CHARACTE	RISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak	SM25GZ51	\/	400	- v	
Off-State Voltage	SM25JZ51	V _{DRM}	600		
R.M.S On-State Current (Full Sine Waveform Tc = 73°C)		I _{T (RMS)}	25	A	
Peak One Cycle Surge On-State		ITSM	230 (50Hz)	A	
	rrent (Non-Repetitive)		253 (60Hz)		
I ² t Limit Value		l ² t	260	A ² s	
Critical Rate of Rise of On-State Current (Note 1)		di / dt	50	A / µs	
Peak Gate Power Dis	sipation	P _{GM}	5	W	
Average Gate Power	Dissipation	P _{G (AV)}	0.5	W	
Peak Gate Voltage		V _{GM}	10	V	
Peak Gate Current		I _{GM}	2	А	
Junction Temperature	9	Tj	-40~125	°C	
Storage Temperature	Range	T _{stg}	-40~125	°C	
Isolation Voltage (AC	. t = 1 min.)	V _{Isol}	1500	V	

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Note 1: di / dt Test Condition V_{DRM} = 0.5 × Rated I_{TM} ≤ 40A t_{gw} ≥ 10µs t_{ar} ≤ 250ns $i_{gp} = I_{GT} \times 2.0$

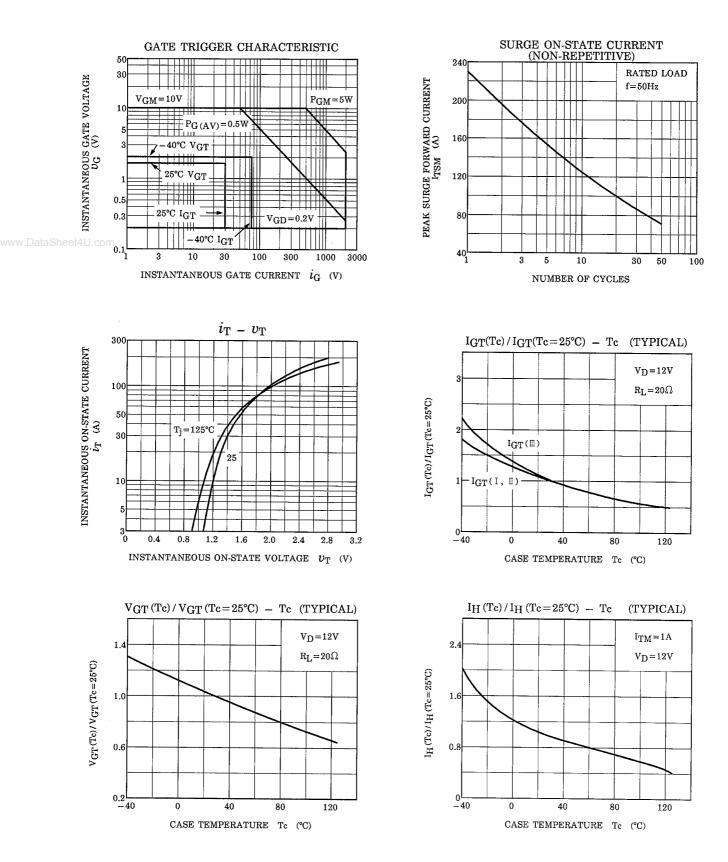
Unit: mm

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

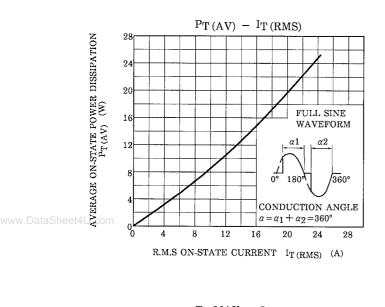
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		-	—	20	μA
Gate Trigger Voltage	Ι	V _{GT}	V _D = 12V R _L = 20Ω	T2 (+) , Gate (+)		_	1.5	v
	П			T2 (+) , Gate (−)	-	_	1.5	
	III			T2 (-) , Gate (-)	_	—	1.5	
Gate Trigger Current	Ι	I _{GT}	V _D = 12V R _L = 20Ω	T2 (+) , Gate (+)	_	—	30	mA
	Ш			T2 (+) , Gate (−)	_	_	30	
	III			T2 (-) , Gate (-)	_	_	30	
Peak On-State Voltage		V _{TM}	I _{TM} = 40A		_	_	1.5	V
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		Ι _Η	V _D = 12V, I _{TM} = 1A		_	_	60	mA
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC		_	_	1.3	°C/W
Critical Rate of Rise of Off-State Voltage		dv / dt	V _{DRM} = Rated, T _j = 125°C Exponential Rise		_	300	_	V / µs
Critical Rate of Rise of Off-State Voltage at Commutation		(dv / dt) c	V _{DRM} = 400V, T _j = 125°C (di / dt) c = – 15A / ms		10	_	_	V / µs

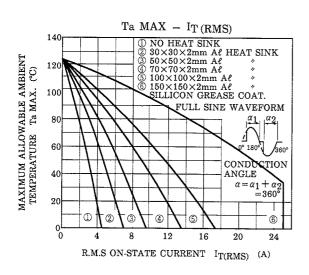
MARKING

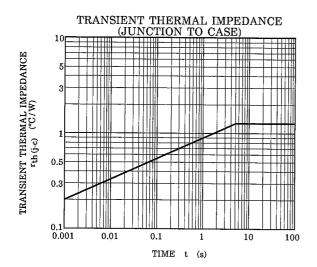
	NUMBER		MARK		
	*1	TYPE	SM25GZ51	M25GZ51	
		1111	SM25JZ51	M25JZ51	
	*2	Lot Number Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)	Example 8A : January 1998 8B : February 1998 8L : December 1998		

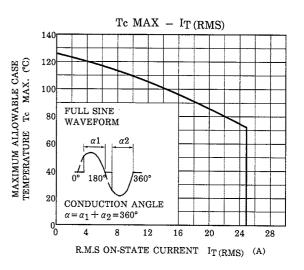


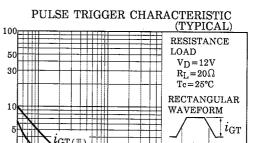
TOSHIBA

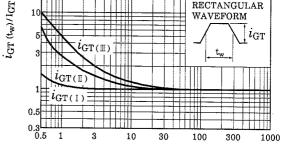












GATE TRIGGER PULSE WIDTH t_w (µs)

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